



# SIEGERT WAFER

Wafer Specialist

SIEGERT WAFER GmbH, Charlottenburger Allee 7, 52068 Aachen

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CZECH REPUBLIC

## Order Acknowledgement

Document No. 213657	Date 20.09.2023	Page 1 / 2
Order No. 002230261	Our Reference <b>34277.kk</b>	
SW Contact	Phone +49 241 943 297-26	
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The detailed Specification can be found on the following page(s)

Currency: EUR

Description	Quantity	Unit	Price	Total
Based on Quotation 137445 / Our Reference 34277.kk				
<b>1 Si-Wafer 4P0/&lt;0.005/525±20/SSP/TTV&lt;5/300nm wet SiO2</b> Lead Time: 2-3 weeks	55	pcs	32,20	1.771,00
<b>2 Dicing of 4" Si-wafers in 20x15 mm<sup>2</sup></b> Lead Time: +4-6 weeks	5	pcs	89,00	445,00
<b>3 Shipping and Packaging (Europe)</b>	1	pc	50,00	50,00

Subtotal	2.266,00
Net Amount	<b>2.266,00</b>
<b>Total (EUR)</b>	<b>2.266,00</b>

**Our Standard Terms and Conditions of Sale and Delivery apply, accessible at [www.terms.siegertwafer.com](http://www.terms.siegertwafer.com)**

We will be glad to provide you with a printed version upon request

INCOTERM 2020	Payment Terms
FCA-Aachen-GER	21 days net

### Remarks

- Please always state our reference number on all documents and in all e-mails: 34277.kk
- Apparent defects must be reported in writing within a period of 5 days from receipt of the goods (Standard Terms and Conditions, clause 8.3)

*Thank you for your order!*



SIEGERT WAFER GmbH  
Charlottenburger Allee 7  
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Bank Name Sparkasse Aachen  
Account 47733993  
Bank Code 39050000  
Swift/BIC AACSD33XXX  
IBAN DE97 3905 0000 0047 7339 93



Item	Specification	Value
1	Diameter:	100 ±0.3 mm
	Material:	Silicon
	Growth:	CZ
	Grade:	Prime
	Type/Dopant:	P/B
	Orientation:	<100> ±0.5°
	Resistivity:	<0.005 Ohm-cm
	Thickness:	525 ±20 µm
	Surface Finish:	Single Side Polished
	Flats:	2, SEMI-Std.
	Primary Flat Location:	@ {110}
	Secondary Flat Location:	90° CW from primary Flat
	TTV:	<5 µm
	Bow:	<30 µm
	Warp:	<30 µm
	Particles ≥0.3 µm:	<15
	Packaging:	Standard Cassettes
	Coating:	3,000 Å ±10% Wet Thermal Oxide
	<b>Attention:</b>	<b>Original particle specification is only valid prior coating</b>
2	Size:	20x15 mm <sup>2</sup> (±0.1 mm)
	Packaging:	Wafer mounted on dicing tape, between frame

